<u>TOSHIBA</u>

TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

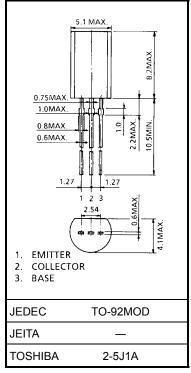
2SA1680

Power Amplifier Applications Power Switching Applications

- Low collector-emitter saturation voltage: V_{CE} (sat) = -0.5 V (max) (I_{C} = -1 A)
- High collector power dissipation: $P_C = 900 \text{ mW}$ (Ta = 25 °C)
- High-speed switching: t_{stg} = 300 ns (typ.)
- Complementary to 2SC4408.

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	-60	V
Collector-emitter voltage	V _{CEO}	-50	V
Emitter-base voltage	V _{EBO}	-6	V
Collector current	Ι _C	-2	А
Base current	Ι _Β	-0.2	А
Collector power dissipation	PC	900	mW
Junction temperature	Tj	150	°C
Storage temperature range	T _{stg}	-55 to 150	°C



Weight: 0.36 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high

temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating

temperature/current/voltage, etc.) are within the absolute maximum ratings.

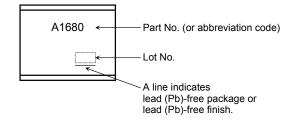
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Unit: mm

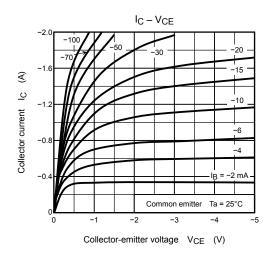
Electrical Characteristics (Ta = 25°C)

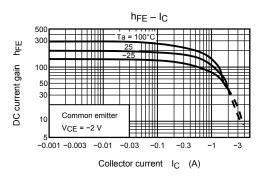
Chara	icteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off c	urrent	I _{CBO}	V _{CB} = -60 V, I _E = 0		—	-1.0	μA
Emitter cut-off cur	rent	I _{EBO}	$V_{EB} = -6 V, I_C = 0$	_	_	-1.0	μA
Collector-emitter	breakdown voltage	V (BR) CEO	I _C = -10 mA, I _B = 0	-50	_	_	V
DC current gain		h _{FE (1)}	$V_{CE} = -2 V, I_C = -100 mA$	120	_	400	
		h _{FE (2)}	V _{CE} = -2 V, I _C = -1.5 A	40	_	_	
Collector-emitter	saturation voltage	V _{CE (sat)}	I _C = -1 A, I _B = -0.05 A	_	-	-0.5	V
Base-emitter satu	ration voltage	V _{BE (sat)}	I _C = -1 A, I _B = -0.05 A	_	_	-1.2	V
Transition frequer	су	fT	$V_{CE} = -2 V, I_C = -100 mA$	_	100	_	MHz
Collector output capacitance		C _{ob}	V _{CB} = -10 V, I _E = 0, f = 1 MHz	_	23	_	pF
	Turn-on time	t _{on}	$20 \ \mu s \qquad \text{Input} \qquad U \ B 20 \ \mu s \qquad \text{Input} \m s \ B 20 \ \mu s \ \text{Input} \qquad U \ B 20 \ \mu s \ \text{Input} \qquad U \ B 20 \ \mu s \ \text{Input} \qquad U \ B 20 \ \mu s \ \text{Input} \m s \ \text{Input}$	_	0.1	_	
	Storage time	t _{stg}		_	0.3	_	μs
	Fall time	t _f		_	0.1		

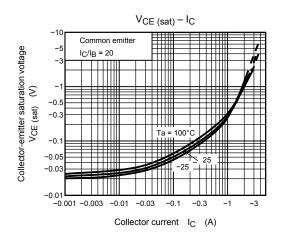
Marking

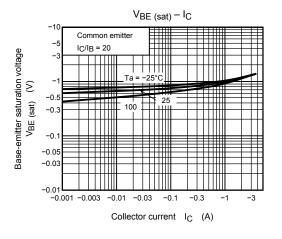


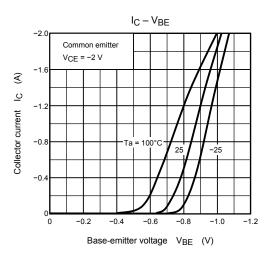
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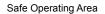


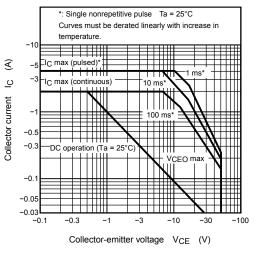












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